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March 2012

FXLA₁₀₈

Low-Voltage Dual-Supply 8-Bit Voltage Translator with Configurable Voltage Supplies and Signal Levels, 3-State Outputs, and Auto Direction Sensing

Features

- Bi-Directional Interface between Two Levels: from 1.1V to 3.6V
- Fully Configurable: Inputs and Outputs Track V_{CC}
- Non-Preferential Power-Up; Either V_{CC} May Be Powered Up First
- Outputs Switch to 3-State if Either V_{CC} is at GND
- Power-Off Protection
- Bus-Hold on Data Inputs Eliminates the Need for Pull-Up Resistors; Do Not Use Pull-Up Resistors on A or B Ports
- Control Input (/OE) Referenced to V_{CCA} Voltage
- Packaged in 20-Terminal DQFN (2.5mm x 4.5mm)
- Direction Control Not Necessary
- 100Mbps Throughput when Translating Between 1.8V and 2.5V
- ESD Protection Exceeds:
 - 8kV HBM (per JESD22-A114 &Mil Std 883e 3015.7)
 - 2kV CDM (per ESD STM 5.3)

Description

The FXLA108 is a configurable dual-voltage supply translator for both uni-directional and bi-directional voltage translation between two logic levels. The device allows translation between voltages as high as 3.6V to as low as 1.1V. The A port tracks the $V_{\rm CCA}$ level and the B port tracks the $V_{\rm CCB}$ level. This allows for bi-directional voltage translation over a variety of voltage levels: 1.2V, 1.5V, 1.8V, 2.5V, and 3.3V.

The device remains in three-state as long as either V_{CC} =0V, allowing either V_{CC} to be powered up first. Internal power-down control circuits place the device in 3-state if either V_{CC} is removed.

The /OE input, when HIGH, disables both the A and B ports by placing them in a 3-state condition. The /OE input is supplied by V_{CCA} .

The FXLA108 supports bi-directional translation without the need for a direction control pin. The two ports of the device have auto-direction sense capability. Either port may sense an input signal and transfer it as an output signal to the other port.

Applications

- Laptops, Notebooks,
- Routers, Switches

Ordering Information

Part Number	Operating Temperature Range	Package	Packing Method
FXLA108BQX	-40 to 85°C	20-Terminal DQFN 2.5mm x 4.5mm Package	3K Units Tape and Reel

Pin Configuration

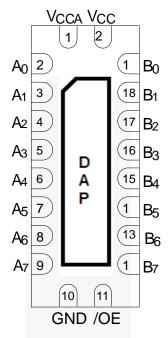


Figure 1. Pin Configuration (Top Through View)

Pin Definitions

Pin#	Name	Description
1	V _{CCA}	A-Side Power Supply
2	A ₀	A-Side Inputs or 3-State Outputs
3	A ₁	A-Side Inputs or 3-State Outputs
4	A ₂	A-Side Inputs or 3-State Outputs
5	A ₃	A-Side Inputs or 3-State Outputs
6	A ₄	A-Side Inputs or 3-State Outputs
7	A ₅	A-Side Inputs or 3-State Outputs
8	A ₆	A-Side Inputs or 3-State Outputs
9	A ₇	A-Side Inputs or 3-State Outputs
10	GND	Ground
11	/OE	Output Enable Input
12	B ₇	B-Side Inputs or 3-State Outputs
13	B ₆	B-Side Inputs or 3-State Outputs
14	B ₅	B-Side Inputs or 3-State Outputs
15	B ₄	B-Side Inputs or 3-State Outputs
16	B ₃	B-Side Inputs or 3-State Outputs
17	B ₂	B-Side Inputs or 3-State Outputs
18	B ₁	B-Side Inputs or 3-State Outputs
19	B ₀	B-Side Inputs or 3-State Outputs
20	V _{CCB}	B-Side Power Supply
DAP	NC	No Connect

Functional Diagram

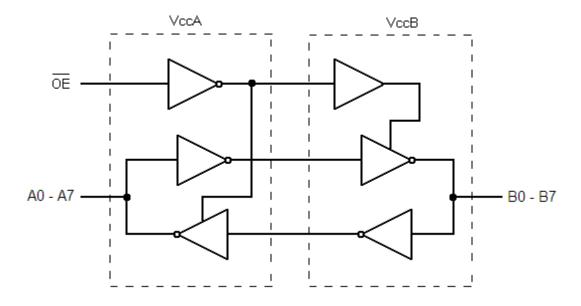


Figure 2. Functional Diagram

Function Table

Control	Outputs
/OE	- Outputs
LOW Logic Level	Normal Operation
HIGH Logic Level	3-State

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameter	Conditions	Min.	Max.	Unit
V	Supply Voltage	V _{CCA}	-0.5	4.6	V
V _{CC}	Supply Voltage	V _{CCB}	-0.5	4.6	V
VI	DC Input Voltage	I/O Ports A and B	-0.5	4.6	V
٧١	DC input voltage	Control Input (/OE)	-0.5	4.6	V
		Output 3-State	-0.5	4.6	
Vo	Output Voltage ⁽²⁾	Output Active (A _n)	-0.5	V _{CCA} +0.5	V
		Output Active (B _n)	-0.5	V _{CCB} +0.5	
I _{IK}	DC Input Diode Current	V _I <0V		-50	mA
_ /	DC Output Diode Current	V _O <0V		-50	mA
I _{OK}	DC Output Diode Current	V _O >V _{CC}		+50	IIIA
I _{OH} /I _{OL}	DC Output Source/Sink Current		-50	+50	mA
I _{CC}	DC V _{CC} or Ground Current (per S	Supply Pin)		±100	mA
T _{STG}	Storage Temperature Range		-65	+150	°C
P_D	Power Dissipation			35	mW
ESD	Human Body Model, JESD22-A1	14		8	kV
ESD	Charged Device Model, JESD22	-C101		2	KV

Notes:

- 1. I_O absolute maximum ratings must be observed.
- 2. All unused inputs and input/outputs must be held at V_{CCi} or GND.

Recommended Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding them or designing to Absolute Maximum Ratings.

Symbol	Parameter	Conditions	Min.	Max.	Unit
V _{CC}	Power Supply	Operating V _{CCA} or V _{CCB}	1.1	3.6	V
V	Innut Valtage	Ports A and B	0	3.6	V
V_{IN}	Input Voltage	Control Input (/OE)	0	V _{CCA}	V
T _A	Operating Temperature, Free Air		-40	+85	°C
dt/dV	Minimum Input Edge Rate	V _{CCA/B} = 1.1 to 3.6V		10	ns/V
Θ_{JA}	Thermal Resistance: Junction-to-Ambient			50	°C/W
$\Theta_{\sf JC}$	Thermal Resistance: Junction-to-Case			23	°C/W

Power-Up/Power-Down Sequence

FXL translators offer an advantage in that either V_{CC} may be powered up first. This benefit derives from the chip design. When either V_{CC} is at 0V, outputs are in a high-impedance state. The control input (/OE) is designed to track the V_{CCA} supply. A pull-up resistor tying /OE to V_{CCA} should be used to ensure that bus contention, excessive currents, or oscillations do not occur during power-up or power-down. The size of the pull-up resistor is based upon the current-sinking capability of the device driving the /OE pin.

The recommended power-up sequence is:

- Apply power to the first V_{CC}.
- 2. Apply power to the second V_{CC} .
- 3. Drive the /OE input LOW to enable the device.

The recommended power-down sequence is:

- 1. Drive /OE input HIGH to disable the device.
- 2. Remove power from either V_{CC} .
- Remove power from other V_{CC}.

Pull-Up/Pull-Down Resistors

<u>Do not use pull-up or pull-down resistors.</u> This device has bus-hold circuits: pull-up or pull-down resistors are not recommended because they interfere with the output state. The current through these resistors may exceed the hold drive, $I_{I(HOLD)}$ and/or $I_{I(OD)}$ bus-hold currents. The bus-hold feature eliminates the need for extra resistors.

DC Electrical Characteristics

 T_A =-40 to 85°C.

Symbol	Parameter	Conditions	V _{CCA} (V)	V _{CCB} (V)	Min.	Тур.	Max.	Unit s	
			2.70 to 3.60		2.00				
			2.30 to 2.70		1.60				
V_{IHA}		Data Inputs A _n Control Pin /OE	1.65 to 2.30	1.10 to 3.60	.65xV _{CCA}			V	
		Control 1 III / OL	1.40 to 1.65		.65xV _{CCA}				
	Liber Level Level Veltere		1.10 to 1.40		.90xV _{CCA}				
	High-Level Input Voltage			2.70 to 3.60	2.00				
		Data Inputs B _n 1	Data Inputs B _n 1.10		2.30 to 2.70	1.60			
V_{IHB}				Data Inputs B _n 1.10 to 3.6	1.10 to 3.60	1.65 to 2.30	.65xV _{CCB}		
				1.40 to 1.65	.65xV _{CCB}				
				1.10 to 1.40	.90xV _{CCB}				
			2.70 to 3.60				.80		
			2.30 to 2.70				.70		
V_{ILA}		Data Inputs A _n Control Pin /OE	1.65 to 2.30	1.10 to 3.60			.35xV _{CCA}	V	
	7	Control 1 III / OL	1.40 to 1.65				.35xV _{CCA}		
Lo	Low-Level Input Voltage		1.10 to 1.40				.10xV _{CCA}		
				2.70 to 3.60			.80		
				2.30 to 2.70			.70		
V_{ILB}		Data Inputs B _n	1.10 to 3.60	1.65 to 2.30			.35xV _{CCB}	V	
						1.40 to 1.65			.35xV _{CCB}
				1.10 to 1.40			.10xV _{CCB}		
V _{OHA}	High-Level Output	I _{OH} =-4μA	1.10 to 3.60	1.10 to 3.60	V _{CCA} 40			.,	
V _{OHB}	Voltage ⁽³⁾	I _{OH} =-4μA	1.10 to 3.60	1.10 to 3.60	V _{CCB} 40			V	
V _{OLA}	Low-Level Output	I _{OL} =4µA	1.10 to 3.60	1.10 to 3.60			.4	.,	
V _{OLB}	Voltage ⁽³⁾	I _{OL} =4µA	1.10 to 3.60	1.10 to 3.60			.4	V	
		V _{IN} =0.80V	3.00	3.00	75.0				
		V _{IN} =2.00V	3.00	3.00	-75.0		7		
		V _{IN} =0.7V	2.30	2.30	45.0				
		V _{IN} =1.60V	2.30	2.30	-45.0		1		
I	Bus-Hold Input Minimum	V _{IN} =0.57V	1.65	1.65	25.0				
I _{I(HOLD)}	Drive Current	V _{IN} =1.07V	1.65	1.65	-25.0			μA	
		V _{IN} =0.49V	1.40	1.40	11.0				
		V _{IN} =0.91V	1.40	1.40	-11.0		TR		
	<u> </u>	V _{IN} =0.11V	1.10	1.10		4.0	11.		
		V _{IN} =0.99V	1.10	1.10		-4.0			

Continued on following page...

DC Electrical Characteristics (Continued)

 T_A =-40 to 85°C.

Symbol	Parameter	Conditions	V _{CCA} (V)	V _{CCB} (V)	Min.	Max.	Units
			3.60	3.60	450.00		
	Bus-Hold Input		2.70	2.70	300.00		
I _{I(ODH)}	Overdrive High	Data Inputs A _n , B _n	1.95	1.95	200.00		μΑ
	Current ⁽⁴⁾		1.60	1.60	120.00		
			1.40	1.40	80.00		
			3.60	3.60	-450.00		
	Bus-Hold Input		2.70	2.70	-300.00		
$I_{I(ODL)}$	Overdrive Low	Data Inputs A _n , B _n	1.95	1.95	-200.00		μΑ
	Current ⁽⁵⁾		1.60	1.60	-120.00		
			1.40	1.40	-80.00		
I	Input Leakage Current	Control Inputs /OE, V _I =V _{CCA} or GND	1.10 to 3.60	3.60		±1.0	μA
. /	Power-Off Leakage	$A_n V_O=0V \text{ to } 3.6V$	0	3.6		±2.0	
I _{OFF}	Current	B _n V _O =0V to 3.6V	3.60	0		±2.0	μA
		A_n , B_n V_O =0V or 3.6V, $/OE$ = V_{IH}	3.6	3.60		±5.0	
l _{OZ}	3-State Output Leakage	A _n V _O =0V or 3.6V, /OE=GND	3.60	0		±5.0	μA
		B _n V _O =0V or 3.6V, /OE=GND	0	3.60		±5.0	
I _{CCA/B}	Quiescent Supply	V _I =V _{CCI} or GND; I _O =0, /OE=GND	1.10 to 3.60	1.10 to 3.60		10.0	μA
I _{ccz}	Current ^(6, 7)	$V_I=V_{CCI}$ or GND; $I_O=0$, $/OE=V_{IH}$	1.10 to 3.60	1.10 to 3.60		10.0	μА
I _{CCA}		V _I =V _{CCB} or GND; I _O =0 B-to-A Direction, /OE=GND	0	1.10 to 3.60		-10.0	μA
30/1	Quiescent Supply	V _I =V _{CCA} or GND; I _O =0 A-to-B Direction	1.10 to 3.60	0		10.0	
I _{CCB}	Current	V _I =V _{CCA} or GND; I _O =0, A-to-B Direction, /OE=GND	1.10 to 3.60	0		-10.0	μA
		V _I =V _{CCB} or GND; I _O =0 B-to-A Direction	0	1.10 to 3.60		10.0	

Notes:

- This is the output voltage for static conditions. Dynamic drive specifications are given in the Dynamic Output Electrical Characteristics table.
- An external drive must source at least the specified current to switch LOW-to-HIGH.
- An external drive must source at least the specified current to switch HIGH-to-LOW.
- V_{CCI} is the V_{CC} associated with the input side. Reflects current per supply, V_{CCA} or $V_{\text{CCB}}.$

Dynamic Output Electrical Characteristic

A Port (A_n)

Output Load: $C_L=15pF$, $R_L \ge M\Omega$ ($C_{I/O}=4pF$), $T_A=-40$ to $85^{\circ}C$

Symbol	Parameter	V _{CCA} =3.0V to 3.6V		V _{CCA} =2.3V to 2.7V		V _{CCA} =1.65V to 1.95V		V _{CCA} =1.4V to 1.6V		V _{CCA} =1.1V to 1.3V	Units
		Тур.	Max.	Тур.	Max.	Тур.	Max	Тур.	Max.	Тур.	
t _{rise}	Output Rise Time A Port ⁽⁹⁾		3.0		3.5		4.0		5.0	7.5	ns
t _{fall}	Output Fall Time A Port ⁽¹⁰⁾		3.0		3.5		4.0		5.0	7.5	ns
I _{OHD}	Dynamic Output Current High ⁽⁹⁾	-11.4		-7.5		-4.7		-3.2		-1.7	mA
I _{OLD}	Dynamic Output Current Low ⁽¹⁰⁾	+11.4		+7.5		+4.7		+3.2		+1.7	mA

B Port (B_n)

Output Load: $C_L=15pF$, $R_L \ge M\Omega$ ($C_{I/O}=5pF$), $T_A=-40$ to $85^{\circ}C$

Symbol	Parameter	V _{CCB} =3.0V to 3.6V		V _{CCB} =2.3V to 2.7V		V _{CCB} =1.65V to 1.95V		V _{CCB} =1.4V to 1.6V		V _{CCB} =1.1V to 1.3V	Units
		Тур.	Max.	Тур.	Max.	Тур.	Max	Тур.	Max.	Тур.	
t _{rise}	Output Rise Time B Port ⁽⁹⁾		3.0		3.5		4.0		5.0	7.5	ns
t _{fall}	Output Fall Time B Port ⁽¹⁰⁾		3.0		3.5		4.0		5.0	7.5	ns
I _{OHD}	Dynamic Output Current High ⁽⁹⁾	-12.0		-7.9		-5.0		-3.4		-1.8	mA
I _{OLD}	Dynamic Output Current Low ⁽¹⁰⁾	+12.0		+7.9		+5.0		+3.4		+1.8	mA

- 8. Dynamic output characteristics are guaranteed, but not tested.
- 9. See Figure 7. 10. See Figure 8.

AC Characteristics

V_{CCA} = 3.0V to 3.6V, T_A =-40 to 85°C

Symbol	Parameter	V _{CCB} =	=3.0V 3.6V		=2.3V 2.7V	V _{CCB} =	1.65V .95V	V _{CCB} :	=1.4V .6V	V _{CCB} =1.1V to 1.3V	Units
		Min.	Max.	Min.	Max.	Min.	Max	Min.	Max.	Тур.	
	A to B	0.2	4.0	0.3	4.2	0.5	5.4	0.6	6.8	6.9	ns
t _{PLH} ,t _{PHL}	B to A	0.2	4.0	0.2	4.1	0.3	5.0	0.5	6.0	4.5	ns
t _{PZL} ,t _{PZH}	/OE to A, /OE to B		1.7		1.7		1.7		1.7	1.7	μs
t _{SKEW}	A Port, B Port ⁽¹¹⁾		0.5		0.5		0.5		1.0	1.0	ns

$V_{CCA} = 2.3V$ to 2.7V, $T_A = -40$ to 85°C

Symbol	Parameter	Parameter V _{CCB} =3.0V to 3.6V		V _{CCB} =2.3V to 2.7V		V _{CCB} =1.65V to 1.95V		V _{CCB} =1.4V to 1.6V		V _{CCB} =1.1V to 1.3V	Units
		Min.	Max.	Min.	Max.	Min.	Max	Min.	Max.	Тур.	
	A to B	0.2	4.1	0.4	4.5	0.5	5.6	0.8	6.9	7.0	ns
t _{PLH} ,t _{PHL}	B to A	0.3	4.2	0.4	4.5	0.5	5.5	0.5	6.5	4.8	ns
t _{PZL} ,t _{PZH}	/OE to A, /OE to B		1.7		1.7		1.7		1.7	1.7	μs
t _{SKEW}	A Port, B Port ⁽¹¹⁾		0.5		0.5		0.5		1.0	1.0	ns

$V_{CCA} = 1.65V$ to 1.95V, $T_A = -40$ to 85°C

Symbol	Parameter		=3.0V 3.6V		=2.3V 2.7V	V _{CCB} =			=1.4V .6V	V _{CCB} =1.1V to 1.3V	Units
		Min.	Max.	Min.	Max.	Min.	Max	Min.	Max.	Тур.	
	A to B	0.3	5.0	0.5	5.5	0.8	6.7	0.9	7.5	7.5	ns
t _{PLH} ,t _{PHL}	B to A	0.5	5.4	0.5	5.6	0.8	6.7	1.0	7.0	5.4	ns
t_{PZL}, t_{PZH}	/OE to A, /OE to B		1.7		1.7		1.7		1.7	1.7	μs
t _{SKEW}	A Port, B Port ⁽¹¹⁾		0.5		0.5		0.5		1.0	1.0	ns

Note:

11. Skew is the variation of propagation delay between output signals and applies only to output signals on the same port (A_n or B_n) and switching with the same polarity (LOW-to-HIGH or HIGH-to-LOW) (see Figure 10). Skew is guaranteed, but not tested.

AC Characteristics (Continued)

V_{CCA} = 1.4V to 1.6V, T_A =-40 to 85°C

Symbol	Parameter		=3.0V 3.6V		=2.3V 2.7V	V _{CCB} =	1.65V .95V		=1.4V .6V	V _{CCB} =1.1V to 1.3V	Units
		Min.	Max.	Min.	Max.	Min.	Max	Min.	Max.	Тур.	
t _{PLH} ,t _{PHL}	A to B	0.5	6.0	0.5	6.5	1.0	7.0	1.0	8.5	7.9	ns
	B to A	0.6	6.8	0.8	6.9	0.9	7.5	1.0	8.5	6.1	ns
t _{PZL} ,t _{PZH}	/OE to A, /OE to B		1.7		1.7		1.7		1.7	1.7	μs
t _{SKEW}	A Port, B Port ⁽¹²⁾		1.0		1.0		1.0		1.0	1.0	ns

$V_{CCA} = 1.1V \text{ to } 1.3V, T_A = -40 \text{ to } 85^{\circ}C$

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Symbol	Parameter	V _{CCB} =3.0V to 3.6V	V _{CCB} =2.3V to 2.7V	V _{CCB} =1.65V to 1.95V	V _{CCB} =1.4V to 1.6V	V _{CCB} =1.1V to 1.3V	Units	
		Тур.	Тур.	Тур.	Тур.	Тур.	į	
	A to B	4.6	4.8	5.4	6.2	9.2	ns	
t _{PLH} ,t _{PHL}	B to A	6.8	7.0	7.4	7.8	9.1	ns	
t_{PZL}, t_{PZH}	/OE to A, /OE to B	1.7	1.7	1.7	1.7	1.7	μs	
t _{SKEW}	A Port, B Port ⁽¹²⁾	1.0	1.0	1.0	1.0	1.0	ns	

Note:

12. Skew is the variation of propagation delay between output signals and applies only to output signals on the same port (A_n or B_n) and switching with the same polarity (LOW-to-HIGH or HIGH-to-LOW) (see Figure 10). Skew is guaranteed, but not tested.

Maximum Data Rate

$T_A=-40$ to 85° C.

V _{CCA}	V _{CCB} =3.0V to 3.6V	V _{CCB} =2.3V to 2.7V	V _{CCB} =1.65V to 1.95V	V _{CCB} =1.4V to 1.6V	V _{CCB} =1.1V to 1.3V	Units
	Min.	Min.	Min.	Min.	Тур.	
V _{CCA} =3.00V to 3.60V	140	120	100	80	40	Mbps
V _{CCA} =2.30V to 2.70V	120	120	100	80	40	Mbps
V _{CCA} =1.65V to 1.95V	100	100	80	60	40	Mbps
V _{CCA} =1.40V to 1.60V	80	80	60	60	40	Mbps
V _{CCA} =1.10V to 1.30V	Тур.	Тур.	Тур.	Тур.	Тур.	
VCCA=1.10V to 1.30V	40	40	40	40	40	Mbps

Notes:

- 13. Maximum data rate is guaranteed, but not tested.
- 14. Maximum data rate is specified in megabits per second (see Figure 9). It is equivalent to two times the F-toggle frequency, specified in megahertz. For example, 100Mbps is equivalent to 50MHz.

Capacitance

Symbol	Parameter	Conditions	T _A =+25°C Typical	Units
C _{IN}	Input Capacitance Control Pin (/OE)	V _{CCA} =V _{CCB} =GND	3	pF
C	Input/Output Canacitance A _n	V _{CCA} =V _{CCB} =3.3V, /OE=V _{CCA}	4	pF
$C_{I/O}$	Input/Output Capacitance B _n	V _{CCA} =V _{CCB} =3.3V, /OE=V _{CCA}	5	þΓ
C_{pd}	Power Dissipation Capacitance	$V_{CCA}=V_{CCB}=3.3V$, $V_{I}=0V$ or V_{CC} , $f=10MHz$	25	pF

I/O Architecture Benefit

The FXLA108 I/O architecture benefits the end user, beyond level translation, in the following three ways:

Auto Direction without an external direction pin.

Drive Capacitive Loads. Automatically shifts to a higher current drive mode only during "Dynamic Mode" or HL / LH transitions.

Lower Power Consumption. Automatically shifts to low-power mode during "Static Mode" (no transitions), lowering power consumption.

The FXLA108 does not require a direction pin. Instead, the I/O architecture detects input transitions on both side and automatically transfers the data to the corresponding output. For example, for a given channel, if both A and B side are at a static LOW, the direction has been established as A \rightarrow B, and a LH transition occurs on the B port; the FXLA108 internal I/O architecture automatically changes direction from A \rightarrow B to B \rightarrow A.

During HL / LH transitions, or "Dynamic Mode," a strong output driver drives the output channel in parallel with a weak output driver. After a typical delay of approximately 10ns – 50ns, the strong driver is turned off, leaving the weak driver enabled for holding the logic state of the channel. This weak driver is called the "bus hold." "Static Mode" is when only the bus hold drives the channel. The

bus hold can be over ridden in the event of a direction change. The strong driver allows the FXLA108 to quickly charge and discharge capacitive transmission lines during dynamic mode. Static mode conserves power, where $I_{\rm CC}$ is typically < $5\mu A$.

Bus Hold Minimum Drive Current

Specifies the minimum amount of current the bus hold driver can source/sink. The bus hold minimum drive current (II_{HOLD}) is V_{CC} dependent and guaranteed in the DC Electrical tables. The intent is to maintain a valid output state in a static mode, but that can be overridden when an input data transition occurs.

Bus Hold Input Overdrive Drive Current

Specifies the minimum amount of current required (by an external device) to overdrive the bus hold in the event of a direction change. The bus hold overdrive (II_{ODH} , II_{ODL}) is V_{CC} dependent and guaranteed in the DC Electrical tables.

Dynamic Output Current

The strength of the output driver during LH / HL transitions is referenced on page 8, Dynamic Output Electrical Characteristics, I_{OHD} , and I_{OLD} .

Test Diagrams

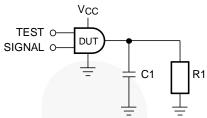


Figure 3. Test Circuit

Table 1. AC Test Conditions

Test	Input Signal	Output Enable Control
t _{PLH} , t _{PHL}	Data Pulses	OV
t _{PZL}	0V	HIGH to LOW Switch
t _{РZН}	V_{CCI}	HIGH to LOW Switch

Table 2. AC Load

V _{CCo}	C1	R1
1.2V± 0.1V	15pF	1ΜΩ
1.5V± 0.1V	15pF	1ΜΩ
1.8V ± 0.15V	15pF	1ΜΩ
2.5V ± 0.2V	15pF	1ΜΩ
$3.3V \pm 0.3V$	15pF	1ΜΩ

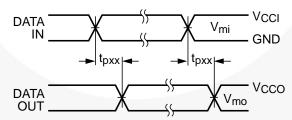


Figure 4. Waveform for Inverting and Non-Inverting Functions

Notes:

15. Input $t_R = t_F = 2.0$ ns, 10% to 90%.

16. Input $t_R = t_F = 2.5 \text{ns}$, 10% to 90%, at $V_I = 3.0 \text{V}$ to 3.6V only.

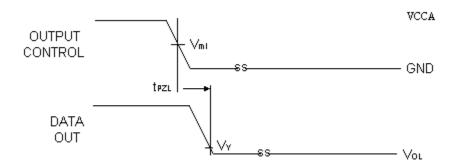


Figure 5. 3-State Output Low Enable Time for Low Voltage Logic

Notes:

- 17. Input $t_R = t_F = 2.0$ ns, 10% to 90%.
- 18. Input $t_R = t_F = 2.5$ ns, 10% to 90%, at $V_I = 3.0$ V to 3.6V only.

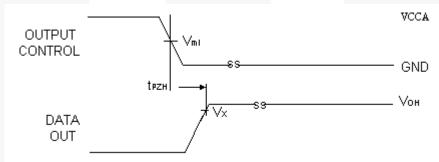


Figure 6. 3-State Output High Enable Time for Low Voltage Logic

Notes:

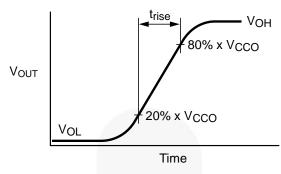
- 19. Input $t_R = t_F = 2.0$ ns, 10% to 90%.
- 20. Input $t_R = t_F = 2.5$ ns, 10% to 90%, at $V_I = 3.0$ V to 3.6V only.

Table 3. Test Measure Points

Symbol	V_{DD}
V _{MI} ⁽²¹⁾	V _{CCI} /2
V_{MO}	V _{CCo} /2
V _X	0.9 x V _{CCo}
V_{Y}	0.1 x V _{CCo}

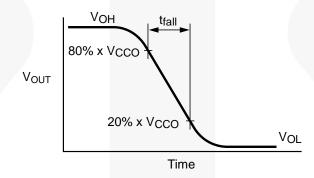
Note:

21. $V_{CCI}=V_{CCA}$ for control pin /OE or $V_{MI}=(V_{CCA}/2)$.



$$I_{OHD} \approx (C_L + C_{I/O}) \times \frac{\Delta V_{OUT}}{\Delta t} = (C_L + C_{I/O}) \times \frac{(20\% - 80\%) \bullet V_{CCO}}{t_{RISE}}$$

Figure 7. Active Output Rise Time and Dynamic Output Current High



$$I_{OLD} \approx (C_L + C_{I/O}) \times \frac{\Delta V_{OUT}}{\Delta t} = (C_L + C_{I/O}) \times \frac{(80\% - 20\%) \bullet V_{CCO}}{t_{FALL}}$$

Figure 8. Active Output Fall Time and Dynamic Output Current Low

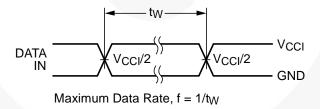


Figure 9. Maximum Data Rate

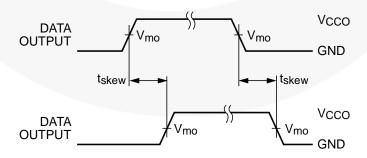
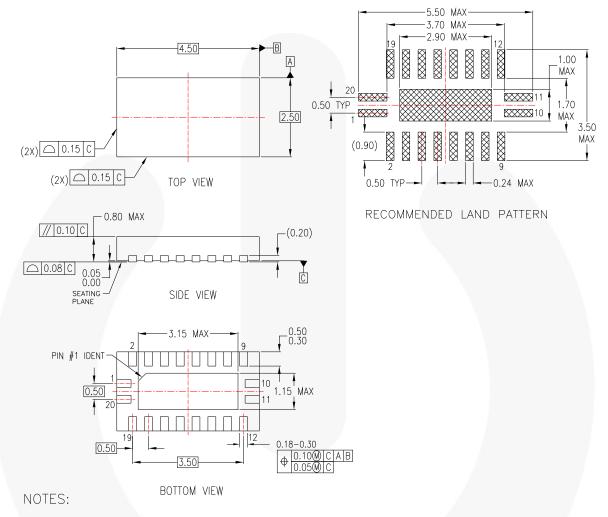


Figure 10. Output Skew Time

Note:

22.
$$t_{SKEW} = (t_{pHLmax} - t_{pHLmin})$$
 or $(t_{pLHmax} - t_{pLHmin})$

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- B. DIMENSIONS ARE IN MILLIMETERS.
- C. DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 1994

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Figure 11. 20-Terminal DQFN 2.5mm x 4.5mm Package

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